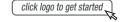


Vishay General Semiconductor

## **Dual Common Cathode Schottky Rectifier**

# ITO-220AB D<sup>2</sup>PAK (TO-263AB) K 2 MBRF15xxCT PIN 10 PIN 2 PIN 20 HEATSINK

#### **DESIGN SUPPORT TOOLS**





PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 7.5 A				
$V_{RRM}$	45 V, 60 V				
I <sub>FSM</sub>	150 A				
$V_{F}$	0.57 V, 0.65 V				
T <sub>J</sub> max.	150 °C				
Package	ITO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Common cathode				

#### **FEATURES**

- Power pack
- Guardring for overvoltage protection



- Low power loss, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB)) package
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B,...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBRB1545CT	MBRB1560CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	45	60		
Working peak reverse voltage		$V_{RWM}$	45	60	V	
Maximum DC blocking voltage		$V_{DC}$	45	60		
Maximum average forward rectified current at $T_c = 105$ °C —	total device	_	15 7.5			
	per diode	I <sub>F(AV)</sub>				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		Α	
Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2.0 μs, 1 kHz		I <sub>RRM</sub>	1.0	0.5		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction temperature range		$T_J$	-65 to +150		°C	
Storage temperature range		T <sub>STG</sub>	-65 to +175			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		$V_{AC}$	1500		V	

# MBRF15xxCT, MBRB15xxCT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB1545CT	MBRB1560CT	UNIT		
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 7.5 A	T <sub>C</sub> = 25 °C	-	0.75	V		
		I <sub>F</sub> = 7.5 A	T <sub>C</sub> = 125 °C	0.57	0.65			
		I <sub>F</sub> = 15 A	T <sub>C</sub> = 25 °C	0.84	-			
		I <sub>F</sub> = 15 A	T <sub>C</sub> = 125 °C	0.72	-			
Maximum instantaneous reverse current at DC blocking voltage per diode	I <sub>R</sub> <sup>(2)</sup>	I <sub>R</sub> <sup>(2)</sup> Rated V <sub>R</sub>	T <sub>C</sub> = 25 °C	0.1	1.0	- mA		
			T <sub>C</sub> = 125 °C	15	50			

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBRF	MBRB	UNIT		
Maximum thermal resistance per diode	$R_{\theta JA}$	-	60	°C/W		
	$R_{ heta JC}$	5.0	3.0	C/VV		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape and reel	
ITO-220AB	MBRF1545CTHE3_A/P (1)	1.99	Р	50/tube	Tube	
TO-263AB	MBRB1545CTHE3_B/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB1545CTHE3_B/I (1)	1.35	I	800/reel	Tape and reel	

#### Note

(1) AEC-Q101 qualified



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#### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

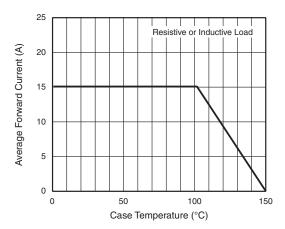


Fig. 1 - Forward Current Derating Curve

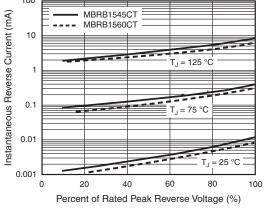


Fig. 4 - Typical Reverse Characteristics Per Diode

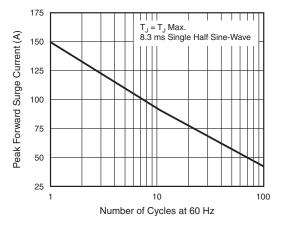


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

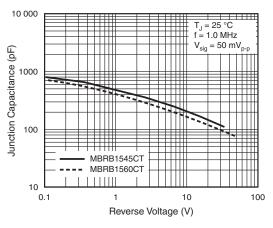


Fig. 5 - Typical Junction Capacitance Per Diode

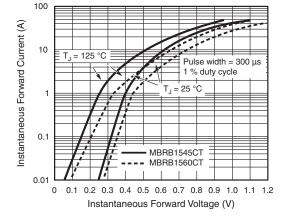


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

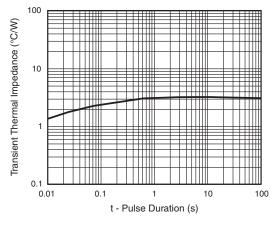
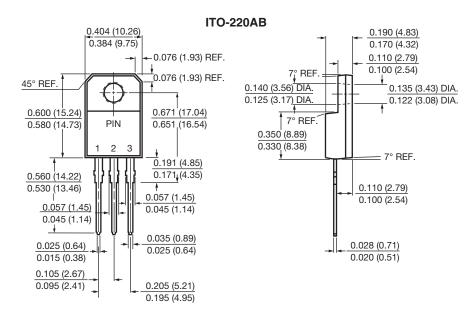


Fig. 6 - Typical Transient Thermal Impedance Per Diode

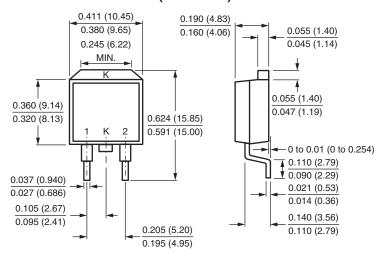


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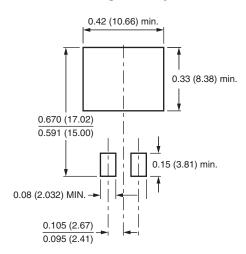
#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



#### D<sup>2</sup>PAK (TO-263AB)



#### **Mounting Pad Layout**





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